

25 A high voltage Triacs

Features

- On-state current ($I_{T(RMS)}$): 25 A
- Max. blocking voltage (V_{DRM}/V_{RRM}): 1200 V
- Gate current (I_{GT}): 150 mA
- Commutation @ 10 V/ μ s: up to 88 A/ms
- Noise immunity: 2 kV/ μ s
- Insulated package:
 - 2,500 V rms (UL recognized: E81734).

Description

The TPDVxx25 series use high performance alternistor technology.

Featuring very high commutation levels and high surge current capability, these devices are well adapted to power control for inductive and resistive loads (motor, transformer...) especially on three-phase power grid. Targeted three-phase applications include heating systems, motor starters, and induction motor speed control (especially for fans).

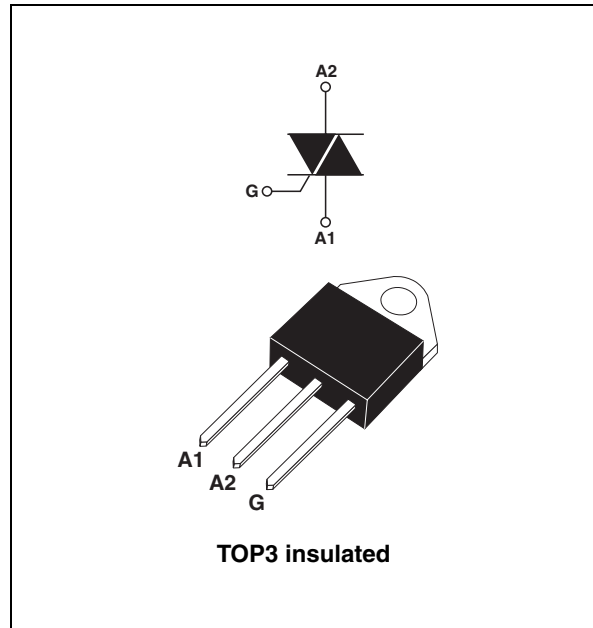


Table 1. Device summary

| Parameter | TPDV825RG | TPDV1025RG | TPDV1225RG |
|------------------------------------|-----------|------------|------------|
| Blocking voltage V_{DRM}/V_{RRM} | 800 V | 1000 V | 1200 V |
| On-state current $I_{T(RMS)}$ | 25 A | | |
| Gate current I_{GT} | 150 mA | | |

1 Characteristics

Table 2. Absolute maximum ratings (limiting values)

| Symbol | Parameter | | Value | Unit | |
|------------------------|---------------------------------------------------------------------------------------------------|-----------------------|-----------------------|--------------------------------|-------------|
| $I_{T(RMS)}$ | On-state rms current (180° conduction angle) | | $T_c = 85\text{ °C}$ | 25 | A |
| I_{TSM} | Non repetitive surge peak on-state current | $t_p = 2.5\text{ ms}$ | $T_j = 25\text{ °C}$ | 390 | A |
| | | $t_p = 8.3\text{ ms}$ | | 250 | |
| | | $t_p = 10\text{ ms}$ | | 230 | |
| I^2t | I^2t value for fusing | $t_p = 10\text{ ms}$ | $T_j = 25\text{ °C}$ | 265 | A^2s |
| di/dt | Critical rate of rise of on-state current $I_G = 500\text{ mA}$, $dI_G/dt = 1\text{ A}/\mu s$ | F = 50 Hz | | 100 | $A/\mu s$ |
| V_{DRM} V_{RRM} | Repetitive peak off-state voltage | TPDV825 | $T_j = 125\text{ °C}$ | 800 | V |
| | | TPDV1025 | | 1000 | |
| | | TPDV1225 | | 1200 | |
| T_{stg} T_j | Storage junction temperature range Operating junction temperature range | | | - 40 to + 150 - 40 to + 125 | $^{\circ}C$ |
| $V_{INS(RMS)}^{(1)}$ | Insulation rms voltage | | | 2500 | V |

1. A1, A2, gate terminals to case for 1 minute

Table 3. Electrical Characteristics ($T_j = 25\text{ °C}$, unless otherwise specified)

| Symbol | Test conditions | | Quadrant | | Value | Unit | |
|------------------------|--------------------------------------------------------------------|-----------------------|-----------------------|-----------------------|-------|-----------|---------|
| I_{GT} | $V_D = 12\text{ V DC}$, $R_L = 33\ \Omega$ | | I - II - III | MAX. | 150 | mA | |
| V_{GT} | | | | MAX. | 1.5 | V | |
| V_{GD} | $V_D = V_{DRM}$ $R_L = 3.3\text{ k}\Omega$ | $T_j = 125\text{ °C}$ | I - II - III | MIN. | 0.2 | V | |
| t_{gt} | $V_D = V_{DRM}$ $I_G = 500\text{ mA}$ $dI_G/dt = 3\text{ A}/\mu s$ | | I - II - III | TYP. | 2.5 | μs | |
| $I_H^{(1)}$ | $I_T = 500\text{ mA}$ Gate open | | | TYP. | 50 | mA | |
| I_L | $I_G = 1.2 \times I_{GT}$ | | I - III | TYP. | 100 | mA | |
| | | | II | | 200 | | |
| dV/dt | Linear slope up to: $V_D = 67\% V_{DRM}$ Gate open | $T_j = 125\text{ °C}$ | | MIN. | 2000 | $V/\mu s$ | |
| $V_{TM}^{(1)}$ | $I_{TM} = 35\text{ A}$ $t_p = 380\ \mu s$ | | | MAX. | 1.8 | V | |
| $V_{to}^{(1)}$ | Threshold voltage | | | MAX. | 1.1 | V | |
| $R_d^{(1)}$ | Dynamic resistance | | | MAX. | 19 | $m\Omega$ | |
| I_{DRM} I_{RRM} | $V_{DRM} = V_{RRM}$ | | | $T_j = 25\text{ °C}$ | MAX. | 20 | μA |
| | | | | $T_j = 125\text{ °C}$ | | 8 | mA |
| $(di/dt)_c^{(1)}$ | $(dV/dt)_c = 200\text{ V}/\mu s$ | | $T_j = 125\text{ °C}$ | MIN. | 20 | A/ms | |
| | $(dV/dt)_c = 10\text{ V}/\mu s$ | | | | 88 | | |

1. For either polarity of electrode A_2 voltage with reference to electrode A_1 .

Table 4. Gate characteristics (maximum values)

| Symbol | Parameter | Value | Unit |
|-------------|--------------------------------|------------------------|------|
| $P_{G(AV)}$ | Average gate power dissipation | 1 | W |
| P_{GM} | Peak gate power dissipation | $t_p = 20 \mu s$ 40 | W |
| I_{GM} | Peak gate current | $t_p = 20 \mu s$ 8 | A |
| V_{GM} | Peak positive gate voltage | $t_p = 20 \mu s$ 16 | V |

Table 5. Thermal resistance

| Symbol | Parameter | Value | Unit |
|------------------|----------------------------------------------------------------------|-------|---------------|
| $R_{th(j-a)}$ | Junction to ambient | 50 | $^{\circ}C/W$ |
| $R_{th(j-c) DC}$ | Junction to case for DC | 1.5 | $^{\circ}C/W$ |
| $R_{th(j-c) AC}$ | Junction to case for 360 $^{\circ}$ Conduction angle ($F = 50 Hz$) | 1.1 | $^{\circ}C/W$ |

Figure 1. Max. rms power dissipation versus on-state rms current ($F = 50Hz$). (curves limited by $(di/dt)_c$)

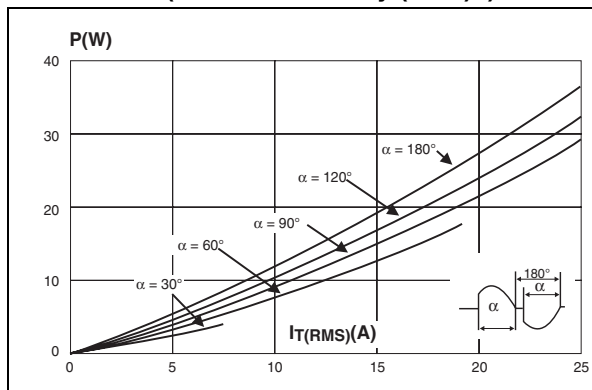


Figure 2. Max. rms power dissipation and max. allowable temperatures (T_{amb} and T_{case}) for various R_{th}

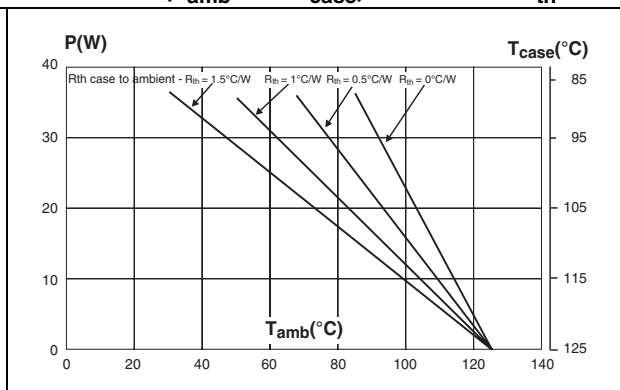


Figure 3. On-state rms current versus case temperature

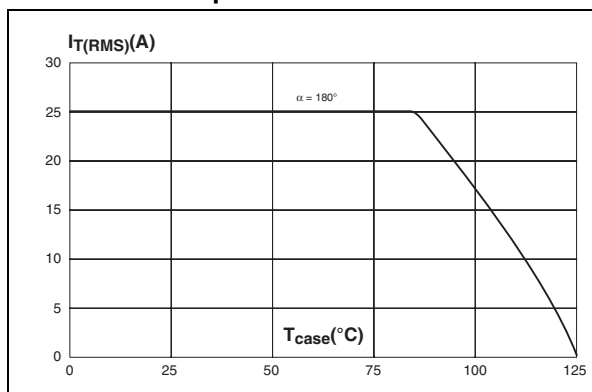


Figure 4. Relative variation of thermal impedance versus pulse duration

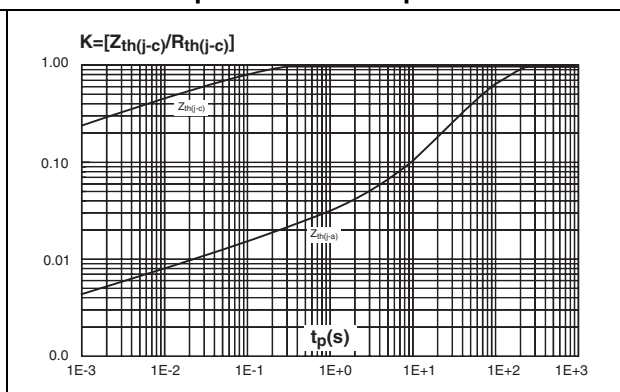


Figure 5. Relative variation of gate trigger current and holding current versus junction temperature

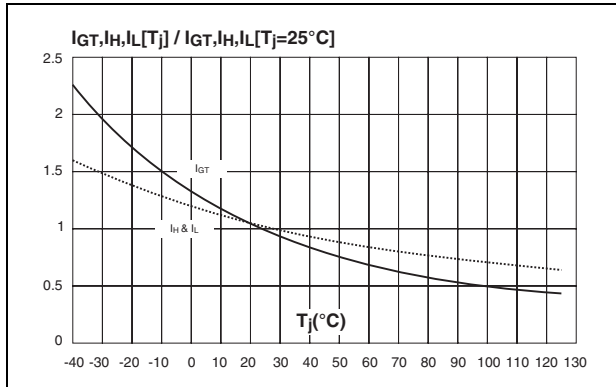


Figure 6. Non repetitive surge peak on-state current versus number of cycles

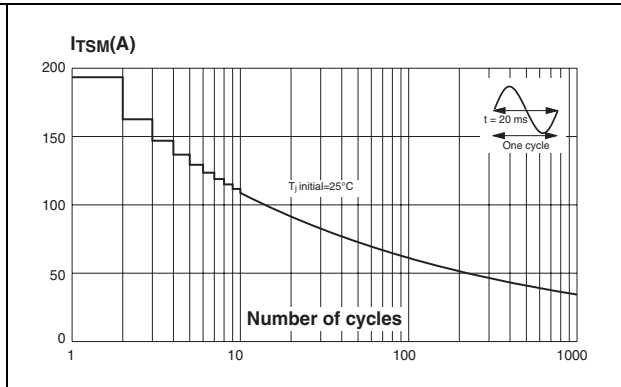


Figure 7. Non-repetitive surge peak on-state current for a sinusoidal pulse and corresponding values of I^2t

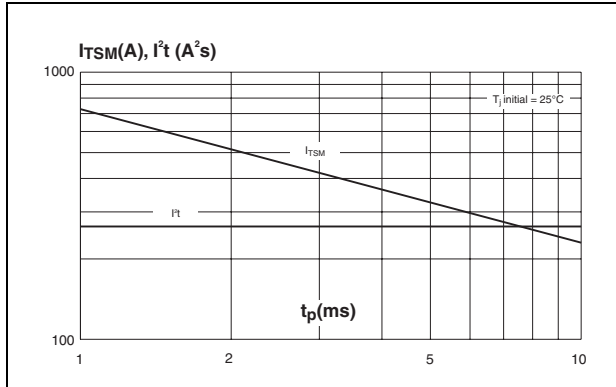


Figure 8. On-state characteristics (maximum values)

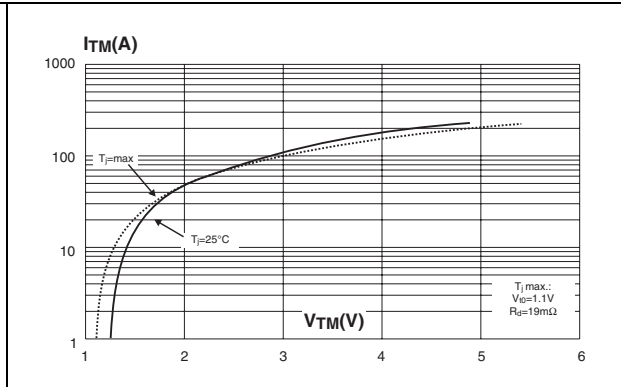
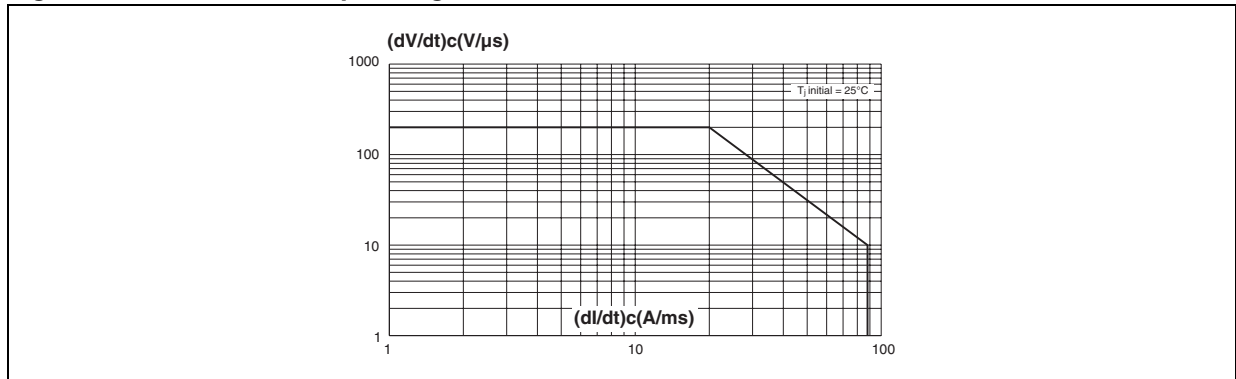


Figure 9. Safe turn-off operating area



2 Package information

- Epoxy meets UL94,V0
- Cooling method: C (by conduction)
- Recommended torque value: 0.9 to 1.2 N·m

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Table 6. TOP3 insulated dimensions

| Ref. | Dimensions | | | |
|------|-------------|-------|------------|-------|
| | Millimeters | | Inches | |
| | Min. | Max. | Min. | Max. |
| A | 4.4 | 4.6 | 0.173 | 0.181 |
| B | 1.45 | 1.55 | 0.057 | 0.061 |
| C | 14.35 | 15.60 | 0.565 | 0.614 |
| D | 0.5 | 0.7 | 0.020 | 0.028 |
| E | 2.7 | 2.9 | 0.106 | 0.114 |
| F | 15.8 | 16.5 | 0.622 | 0.650 |
| G | 20.4 | 21.1 | 0.815 | 0.831 |
| H | 15.1 | 15.5 | 0.594 | 0.610 |
| J | 5.4 | 5.65 | 0.213 | 0.222 |
| K | 3.4 | 3.65 | 0.134 | 0.144 |
| ØL | 4.08 | 4.17 | 0.161 | 0.164 |
| P | 1.20 | 1.40 | 0.047 | 0.055 |
| R | 4.60 typ. | | 0.181 typ. | |

3 Ordering information

Table 7. Ordering information

| Order code | Marking | Package | Weight | Base qty | Delivery mode |
|------------|----------|-------------------|--------|----------|---------------|
| TPDV825RG | TPDV825 | TOP3 insulated | 4.5 g | 30 | Tube |
| TPDV1025RG | TPDV1025 | | | | |
| TPDV1225RG | TPDV1225 | | | | |

4 Revision history

Table 8. Document revision history

| Date | Revision | Changes |
|-------------|----------|------------------------------------------------------------------------------------------------------|
| 30-Mar-2011 | 1 | First issue. |
| 13-Jan-2012 | 2 | Updated dl/dt in Table 2 and added V_{to} and R_d to Table 3 . |

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